

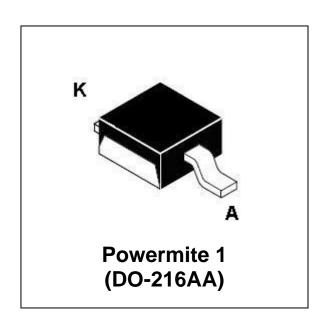
Low Leakage Schottky Barrier Rectifier

Main product characteristics

Io	1A		
V_{RRM}	20V		
$T_{j(MAX)}$	125°C		
$V_{F(MAX)}$	0.455V		
I _{R(MAX)}	10μΑ		

Features and benefits

- Low forward voltage drop
- Low profile package height
- Efficient heat path with integral locking bottom metal tab
- Low thermal resistance DO-216AA package



Description and applications

Single schottky rectifier assembled in Powermite 1[®] package which features a full metallic bottom that eliminates possibility of solder flux entrapment during assembly. The package also incorporates a unique locking tab which acts as an efficient heat path from die to mounting plane for external heat sinking with very low thermal resistance junction to case (bottom).

This product is suitable for use in switching and regulating power supplies and also charge pump circuits.

Absolute maximum ratings⁽¹⁾

Symbol	Parameter	Value	Unit	
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	20	V	
$V_{R(RMS)}$	RMS Reverse Voltage	14	V	
Io	Average rectified forward output current (T _C = 135°C)	1.0	Α	
I _{FRM}	Peak repetitive forward current (100kHz square wave, T _C = 135°C)	2.0	Α	
I _{FSM}	Non repetitive peak forward surge current (8.3ms single half sine wave)	50	А	
dV/dt	Voltage rate of change (at max V _R)	10000	V/µs	
T _{STG}	Storage temperature	-55 to +150	°C	
T _J	Junction temperature	-55 to +125	°C	

⁽¹⁾ All ratings at 25°C unless specified otherwise





Low Leakage Schottky Barrier Rectifier

Characteristics

Static Electrical Characteristics

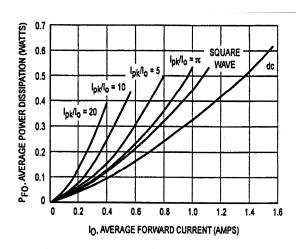
Symbol	Parameter	Test Conditions		Тур	max	Units
V _F ⁽²⁾ Ma	Maximum forward voltage	T _J = 25°C	$I_F = 0.1 A$		0.455	V
			I _F = 1.0 A		0.530	
			I _F = 3.0 A		0.595	
		T _J = 100°C	I _F = 0.1 A		0.360	
			I _F = 1.0 A		0.455	
			I _F = 3.0 A		0.540	
I _R ⁽²⁾ Maximum instantaneou reverse current		T _J = 25°C	$V_{R} = 20V$		10	μΑ
			V _R = 10V		1.0	
	Maximum instantaneous		$V_R = 5V$		0.5	
	reverse current	T _J = 100°C	$V_{R} = 20V$		1600	
			V _R = 10V		500	
			$V_R = 5V$		300	
C_T	Junction capacitance	V _R = 5V, f = 1MHz				pF

⁽²⁾ Measured with a test pulse of 380µs to minimize self-heating effect

Thermal Characteristics

Symbol	Parameter	Value	Unit	
R _{OJC}	Junction to case (bottom)	15	°C/W	
R _{⊝JA}	Junction to ambient ⁽³⁾	240	°C/W	

⁽³⁾ Mounted on FR-4 PC board using 1oz copper with recommended minimum foot print



Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T_J therefore must include forward and reverse power effects. The allowable operating T_J may be calculated from the equation:

$$T_J = T_{J \text{ max}} = r(t)(Pf+Pr)$$
 where

r(t) = thermal impedance under given conditions.

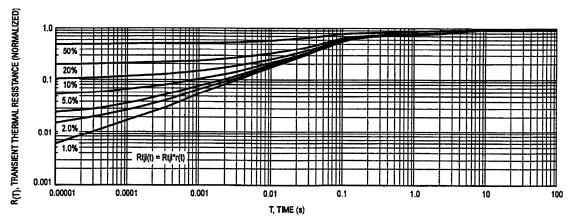
Pf = forward power dissipation, and

Pr = reverse power dissipation

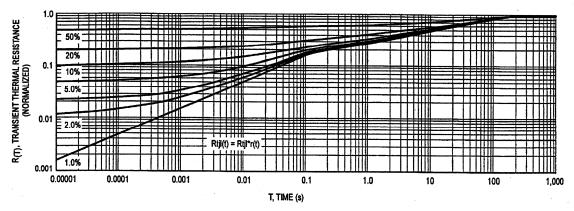
This graph displays the de-rated allowable T_J due to reverse bias under DC conditions only and is calculated as $T_J = T_{J\,max}$ -r(t) Pr, Where r(t)=Rthja. For other power applications further calculations must be performed.



Low Leakage Schottky Barrier Rectifier



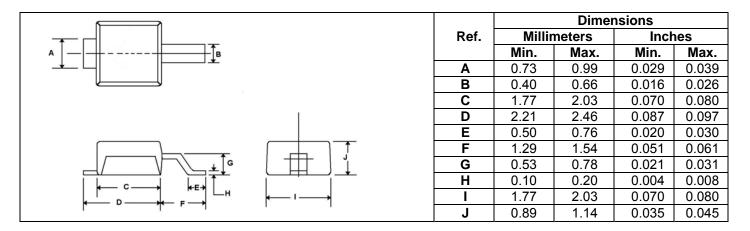
Thermal Impedance Junction to Case (bottom)



Thermal Impedance Junction to Ambient

Mechanical Characteristics

Physical dimensions

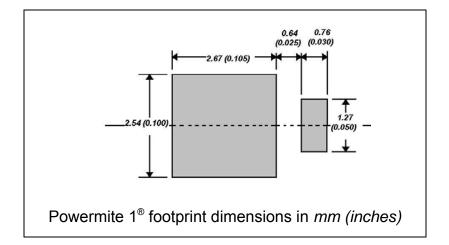




UPS120Ee3

Low Leakage Schottky Barrier Rectifier

Footprint dimensions



Package materials & information

Case: Epoxy meets UL94V-0

Electrode finish: Matte Sn plating - fully RoHS compliant

Marking code:

20E

Ordering information

Product order code	Marking	Package	Weight	Base qty	Delivery mode
UPS120Ee3 / TR7	20E	Powermite 1 (DO-216AA)	0.016 g	3000	Tape and reel (7 inch)
UPS120Ee3 / TR13	20E	Powermite 1 (DO-216AA)	0.016 g	12000	Tape and reel (13 inch)

Commercial Business Unit Microsemi Corporation

Microsemi Commercial Offshore de Macau Limitada Avenida Doutor Mario Soares Bank of China Building, 18/F, Unit D Macau SAR

Please refer to www.microsemi.com for the terms and conditions of purchase

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Microsemi manufacturer:

Other Similar products are found below:

CUS06(TE85L,Q,M) MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR30H100MFST1G MMBD301M3T5G PMAD1103-LF PMAD1108-LF RB160M-50TR RB520S-30 RB551V-30 DD350N18K DZ435N40K DZ600N16K BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327 IDL02G65C5XUMA1 NSR05F40QNXT5G NSVR05F40NXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SBAT54CWT1G SBM30-03-TR-E SBS818-TL-E SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS 70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK110-LTP